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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/982,954	10/22/2001	Gurtej Sandhu	M4065.0353/P353-A	8784
24998	7590	02/23/2006		
DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP			EXAMINER	
2101 L Street, NW			MOORE, KARLA A	
Washington, DC 20037			ART UNIT	PAPER NUMBER

1763

DATE MAILED: 02/23/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

## Office Action Summary

Application No.

09/982,954

Applicant(s)

SANDHU ET AL.

Examiner

Karla Moore

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE \_\_\_\_\_ MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

### Status

- 1) ☒ Responsive to communication(s) filed on 12 December 2005.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

### Disposition of Claims

- 4) ☒ Claim(s) 1,6-13,16,17 and 46-52 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1,6-13,16,17 and 46-52 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 22 October 2001 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

### Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
- ☐ Certified copies of the priority documents have been received.
  - ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  - ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.

### Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)  
Paper No(s)/Mail Date \_\_\_\_\_
- 4) ☐ Interview Summary (PTO-413)  
Paper No(s)/Mail Date. \_\_\_\_\_
- 5) ☐ Notice of Informal Patent Application (PTO-152)
- 6) ☐ Other: \_\_\_\_\_

## DETAILED ACTION

### ***Claim Rejections - 35 USC § 112***

1. The following is a quotation of the second paragraph of 35 U.S.C. 112:  
  
The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
2. Claim 52 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. The claim recites the limitation "the vertical inert gas curtain". There is insufficient antecedent basis for this limitation in the claim.

### ***Claim Rejections - 35 USC § 103***

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:  
  
(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.
4. Claims 1, 6-8, 10-17 and 49 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,071,670 to Kelly in view of U.S. Patent No. 5,935,334 to Fong et al.
5. Kelly discloses an apparatus *capable* of atomic layer deposition, comprising: a plurality of deposition regions (Figure 1, e1 and e2), each of said regions comprising at least one gas exhaust port (24 and 26), wherein each of said plurality of regions are chemically isolated from one another by vertical inert gas curtains (column 2, rows 64-66 and column 4, rows 41-45), and wherein each of said processes are different from one another; and a central loading robot assembly (104) for moving a first substrate laterally through at least one of said vertical inert gas curtains.
6. Examiner notes that although the gas curtains are not explicitly disclosed as vertical, they must be in order to effectively isolate the regions. One of ordinary skill in the art would recognize this.

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7. However, Kelly fail to teach a first atomic layer region used for deposition and a second atomic layer region used for thermal diffusion of the dopant species.

8. Fong et al. teach deposition of a dopant species in a first processing region and transfer to a second processing region, such as an annealing chamber or a rapid thermal process reactor, for the purpose of driving in the dopant atoms (column 41, row 61 through column 42, 12).

9. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a first atomic layer doping region for deposition and a second atomic layer doping region for thermal treatment in King in order to diffuse the dopant atoms as taught by Fong et al.

10. With respect to claims 6-8, 10-13 and 16-17, similar to the claimed invention, the central loading robot assembly is capable of moving a plurality of substrates laterally through four regions sequentially or in a predefined pattern (see Figures 4A and 4B). Thus, a plurality of substrates can be treated simultaneously in respective pairs of first and second regions and then transferred to another plurality of regions. With respect to each of the regions containing a different processing gas, they are capable as taught at column 7, rows 22-25.

11. With respect to claim 49, each of said regions are separate reaction chambers and wherein the reaction chambers are separated by the vertical inert gas curtains.

12. Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Kelly and Fong et al. as applied to claims 1, 6-8, 10-17 and 49 above, and further in view of U.S. Patent No. 6,207,005 B1 to Henley et al.

13. Kelly and Fong et al. disclose the invention substantially as claimed and as described above.

14. However, Kelly and Fong et al. fail to teach an apparatus comprising a third pair of atomic layer doping regions.

15. Henley et al. disclose a deposition apparatus comprising 3 pairs of deposition regions (Figure 1) where increased through put is the result.

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16. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided an additional pair of deposition regions in Kelly and Fong et al. in order to increase the throughput of the deposition apparatus as taught by Henley et al.

17. Claims 46 and 50 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,071,670 to Kelly in view of U.S. Patent No. 5,935,334 to Fong et al. and European Patent Application No. 0 060626 to Gattuso et al.

18. Kelly discloses an apparatus *capable* of atomic layer deposition, comprising: a plurality of deposition regions (Figure 1, e1 and e2), each of said regions comprising at least one gas exhaust port (24 and 26), wherein each of said plurality of regions are chemically isolated from one another by vertical inert gas curtains (column 2, rows 64-66 and column 4, rows 41-45), and wherein each of said processes are different from one another; and a central loading robot assembly (104) for moving a first substrate laterally through at least one of said vertical inert gas curtains.

19. Examiner notes that although the gas curtains are not explicitly disclosed as vertical, they must be in order to effectively isolate the regions. One of ordinary skill in the art would recognize this.

20. However, Kelly fails to teach a first atomic layer region used for deposition and a second atomic layer region used for thermal diffusion of the dopant species.

21. Fong et al. teach deposition of a dopant species in a first processing region and transfer to a second processing region, such as an annealing chamber or a rapid thermal process reactor, for the purpose of driving in the dopant atoms (column 41, row 61 through column 42, 12).

22. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a first atomic layer doping region for deposition and a second atomic layer doping region for thermal treatment in Kelly in order to diffuse the dopant atoms as taught by Fong et al.

23. Kelly and Fong et al. disclose the invention substantially as claimed and as described above.

24. However, Kelly and Fong et al. to teach an inert gas curtain provided at a higher pressure than said first dopant species.

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25. Gattuso et al. teach the use of an inert gas curtain provided at a pressure somewhat higher than that of the reaction gases within the chamber to create an effective, non-reactive gas curtain (abstract).

26. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided an inert gas curtain at a higher pressure than the reaction gases in Kelly and Fong et al. in order to create an effective and non-reactive gas curtain as taught by Gattuso et al.

27. With respect to claim 50, each of said regions are separate reaction chambers and wherein the reaction chambers are separated by the vertical inert gas curtains.

28. Claims 47 and 51 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,071,670 to Kelly in view of U.S. Patent No. 5,935,334 to Fong et al. further in view of U.S. Patent No. 5,382,126 to Hartig et al.

29. Kelly discloses an apparatus *capable* of atomic layer deposition, comprising: a plurality of deposition regions (Figure 1, e1 and e2), each of said regions comprising at least one gas exhaust port (24 and 26), wherein each of said plurality of regions are chemically isolated from one another by vertical inert gas curtains (column 2, rows 64-66 and column 4, rows 41-45), and wherein each of said processes are different from one another; and a central loading robot assembly (104) for moving a first substrate laterally through at least one of said vertical inert gas curtains.

30. Examiner notes that although the gas curtains are not explicitly disclosed as vertical, they must be in order to effectively isolate the regions. One of ordinary skill in the art would recognize this.

31. However, Kelly fails to teach a first atomic layer region used for deposition and a second atomic layer region used for thermal diffusion of the dopant species.

32. Fong et al. teach deposition of a dopant species in a first processing region and transfer to a second processing region, such as an annealing chamber or a rapid thermal process reactor, for the purpose of driving in the dopant atoms (column 41, row 61 through column 42, 12).

33. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a first atomic layer doping region for deposition and a second atomic layer doping region for thermal treatment in Kelly in order to diffuse the dopant atoms as taught by Fong et al.

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34. Examiner realizes that the prior art fails to explicitly teach the use of a non-reactive gas in a second region. However, this is seen as an intended use of which the prior art would be capable. The courts have ruled that expressions relating the apparatus to the contents thereof during an intended operation are of no significance in determining the patentability of the apparatus claim. *Ex parte Thibault*, 164 USPQ 666, 667 (Bd. App. 1969).

35. Kelly and Fong et al. disclose the invention substantially as claimed and as described above.

36. However, Kelly and Fong et al. fail to teach a separate gas exhaust for each region in a multi-chamber coating apparatus.

37. Hartig et al. teach the use of separate gas exhausts in each chamber for the purpose of aspirating gas from each chamber and further preventing gas transfer between the individual chambers (column 2, rows 17-22).

38. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided separate exhaust mechanisms in each chamber in Kelly and Fong et al. in order to aspirate each chamber and further prevent gas transfer between the individual chambers as taught by Hartig et al.

39. With respect to claim 51, each of said regions are separate reaction chambers and wherein the reaction chambers are separated by the vertical inert gas curtains.

40. Claim 48 is rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,314,538 to Maeda et al. in view of U.S. Patent No. 5,935,334 to Fong et al.

41. Maeda et al. disclose a deposition apparatus *capable* of atomic layer deposition, substantially as claimed and comprising, a first deposition region (Figure 2, at "b") for depositing a first gas species on a first substrate as a monolayer, wherein the first deposition region has a first reactive gas supply inlet (38b) located at a first upper position and a first exhaust outlet (40b) connected to a first exhaust system (45b) situated at an opposite position from said first reactive gas supply inlet; a second deposition region (at "c"; also see column 7, rows 20-24) for depositing a second gas species on said first substrate as a monolayer, said first and second deposition regions being chemically isolated from one another by a

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physical barrier having a closeable opening (not shown; column 4, rows 54-57) located between adjacent sidewalls of said first and second deposition regions, wherein the second deposition region has a second reactive gas supply inlet; and a central loading robot assembly (multiple part numbers; 33 and 34 a-f) for moving said first substrate from said first deposition region to said second deposition region through said closeable opening of said physical barrier. Although not explicitly disclosed, the physical barriers would obviously be oriented vertically in order perform their necessary function of isolation between regions.

42. However, Maeda et al. fail to teach a first atomic layer region used for deposition and a second atomic layer region used for thermal diffusion of the dopant species.

43. Fong et al. teach deposition of a dopant species in a first processing region and transfer to a second processing region, such as an annealing chamber or a rapid thermal process reactor, for the purpose of driving in the dopant atoms (column 41, row 61 through column 42, 12).

44. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a first atomic layer doping region for deposition and a second atomic layer doping region for thermal treatment in Maeda et al. in order to diffuse the dopant atoms as taught by Fong et al.

### ***Response to Arguments***

45. Applicant's arguments with respect to claims 1, 6-13, 16-17 and 46-52 have been considered but are moot in view of the new ground(s) of rejection. Each of the claims contains newly added limitations which are addressed in the rejections above. Applicant's arguments regarding the prior rejections are obsolete.

### ***Conclusion***

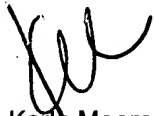
Any inquiry concerning this communication or earlier communications from the examiner should be directed to Karla Moore whose telephone number is 571.272.1440. The examiner can normally be reached on Monday-Friday, 9:00 am-6:00 pm.



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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571.272.1435. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



Karla Moore  
Patent Examiner  
Art Unit 1763  
21 February 2006